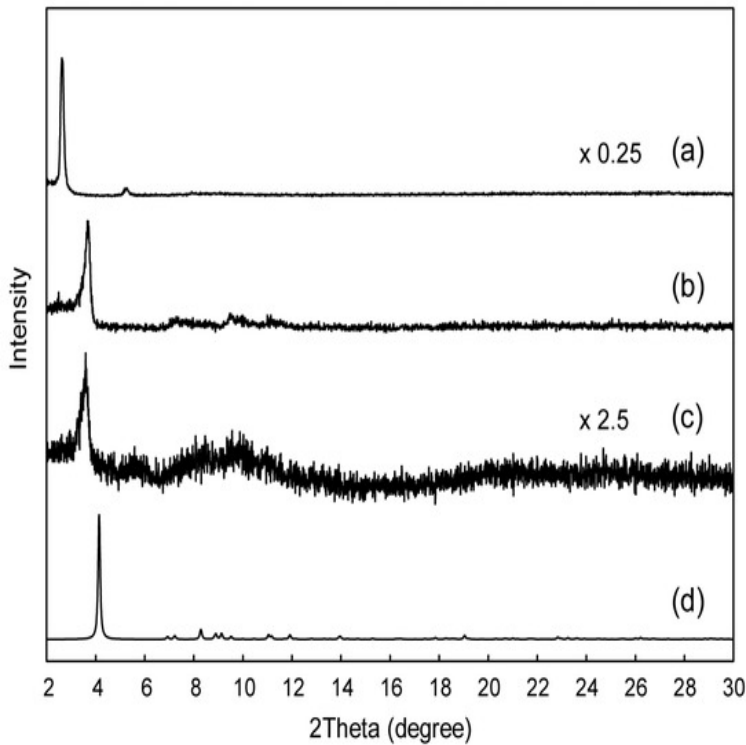


Photodetectors: Materials And Devices III 28-30 January 1998, San Jose, California



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